LETTER

Determination of the crack-tip toughness in silicon nitride ceramics

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Fracture in most ceramic starts from natural cracks with sizes a_0 in the order of a few 10 μ m introduced during the processing of these materials. A crack in a component starts to propagate when the externally applied stress intensity factor K_{appl} exceeds the so-called crack-tip toughness K_{IO} . In the absence of an increasing crack growth resistance, the strength σ_c is exclusively governed by K_{I0} according to

$$
\sigma_{\rm c} = \frac{K_{\rm 10}}{Y\sqrt{a_0}}, \quad Y \cong 1.3 \tag{1}
$$

Many ceramic materials exhibit the effect of an increasing crack growth resistance during crack extension Δa , i.e. a rising R-curve with $K_R = f(\Delta a)$ (Fig. [1](#page-1-0)a). In cases of a moderately rising R-curve, Eq. 1 remains valid. Only in cases of strongly rising R-curves, the strength is affected. For materials with a sufficiently steep R-curve, stable crack extension follows under increasing load. Failure of the component then occurs when the so-called tangent condition is fulfilled, i.e. when the slope of the applied stress intensity factor $K_{\text{appl}}(a)$ and the R-curve $K_{\text{IR}}(a)$ are identical

$$
K_{\text{appl}} = K_{\text{R}}, \quad \frac{\text{d}K_{\text{appl}}}{\text{d}a} = \frac{\text{d}K_{\text{R}}}{\text{d}a} \Rightarrow \sigma_{\text{c}} = f(a_0, K_{\text{R}}) \tag{2}
$$

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The stress intensity factor at which (2) is fulfilled is called "fracture toughness" K_{Ic} , which is introduced in Fig. [1a](#page-1-0) as a triangle.

It follows from (2) that failure behavior in the presence of R-curve behavior can be assessed only if both the shape of the initial R-curve and the crack-tip toughness K_{10} are known.

For high-strength applications, silicon nitride ceramics are of highest importance. Therefore, many R-curve measurements on this material class were carried out in literature with the general result of the occurrence of very steep R-curves. Nevertheless, only a few data for K_{IO} are available. The main reason of this lack is the fact that the range of Δa in which $K_{\rm R}$ rises from $K_{\rm I0}$ to the saturation value K_{Rmax} (Fig. [1a](#page-1-0)) is extremely short and, consequently, an extrapolation of the R-curve to $\Delta a = 0$ is hardly possible.

An independent method to measure K_{10} is the evaluation of crack-opening displacements (COD). Measurements by Pezzotti et al. [[1\]](#page-3-0) on an Al_2O_3 and Y_2O_3 containing $Si₃N₄$ produced via gas-pressure sintering yielded $K_{I0} = 2.7$ MPa \sqrt{m} . From COD for a sintered reactionbonded silicon nitride (SRBSN) by Kounga Njiwa et al. [\[2](#page-3-0)], a range of 1.45 MPa_{$\sqrt{m} \le K_{10} \le 1.95$ MPa \sqrt{m} could} be concluded. For yttria doped material used in the present study, Kruzic et al. [\[3](#page-3-0)] determined $K_{10} = 1.4 \text{ MPa}\sqrt{\text{m}}$ by use of a Raman spectroscopy method. In this article, two $Si₃N₄$ ceramics containing (Y₂O₃, MgO) and -(Y₂O₃, Al₂O₃) are studied by COD measurements.

Material (I) was a silicon nitride which was consolidated in a two-step sintering process. The powder mixture of silicon nitride, 5 wt% Y_2O_3 , and 2 wt% MgO was prepared by attrition milling in isopropanol and afterwards dried and sieved. Greenbodies (45 \times 64 \times 6 mm) were uniaxially pressed and subsequently cold isostatically densified. The

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samples were sintered in a hot isostatic press. In the first step with a low N_2 pressure of 1 MPa, the sample was sintered to achieve closed porosity at a temperature of 1750 °C. Full density was achieved in the HIP step at an N_2 pressure of 20 MPa and a temperature of 1800 °C. Material (II) is a commercial silicon nitride containing Y_2O_3 and Al_2O_3 (SL200BG, CeramTec, Plochingen, Germany).

The R-curves for these materials were measured in a very stiff test device as described in Ref. [[4\]](#page-3-0). Four-point bending tests were carried out on notched bars of dimensions $W = 4$ mm, $B = 3$ mm with the support rollers distances of 10 and 20 mm. The procedure used for silicon nitride was demonstrated in Ref. [\[5\]](#page-3-0) for a specimen of material (1) with a notch length $a_0 = 2.75$ mm and notch root radius of $R = 6.2$ µm introduced with the razor blade procedure.

Incremental stable crack growth is achieved automatically by a computer aided control system. In the very first part of the tests, the R-curve was determined by

compliance evaluation including the effect of the notch on stress intensity factor and compliance.

Figure 1b shows the results for the first microns of crack propagation. It can be seen that the R-curves raise very steeply reaching saturation already after a few µm crack extension. A saturation value of about $K_R \approx 7 \text{ MPa}\sqrt{\text{m}}$ for material (I) is reached even after 10 μ m crack propagation.

For the determination of the starting point of the R-curve, K_{10} , Vickers indentation tests were performed on polished surfaces with an indentation load of 98.8 N with a dwelling time of 15 s. Before the indentation tests, the surfaces were polished up to $1 \mu m$ diamond slurry and afterwards slightly plasma etched for 1 min with a 4:2 $CF_4:O_2$ gas mixture.

Since the semi-elliptical crack shape of Vickers cracks develops in the unloading phase, these cracks are characterized by the condition of $K = K_{10}$ at the crack tip after load removal. Figure 2a illustrates the quadratic impression

of the indenter with diagonal $2b$ and the cruciform semicircular crack system with diameter 2a. The total crack opening 2δ has to be measured under the scanning electron microscope (SEM).

In order to determine the actually present stress intensity factor after unloading, a relation between COD and stress intensity factor is necessary. An analytical solution for the COD of Vickers indentation cracks was given in Ref. [\[6](#page-3-0)].

Fig. 3 a SEM image of the near-tip region of a Vickers indentation (material I) and b near-tip opening for a Vickers indentation crack introduced in a non-etched surface

Fig. 4 a Measured CODs \sqrt{a} plotted versus the displacements computed by Eqs. 3–5 for a stress intensity factor of $K = 1$ MPa \sqrt{m} , and **b** near-tip data; solid straight line: leastsquares fit (the dash-dotted straight lines border the region including 66% of the data points)

$$
\frac{\delta}{K} = \frac{\sqrt{b}}{E'} \left(\sqrt{\frac{8}{\pi}} \frac{x}{b} + A_1 \left(\frac{x}{b}\right)^{3/2} + A_2 \left(\frac{x}{b}\right)^{5/2} \right) \tag{3}
$$

with the coefficients A_1 and A_2 fitted as

$$
A_1 \cong 11.7 \exp[-2.063(a/b-1)^{0.28}] - \frac{0.898}{a/b-1},
$$
 (4)

$$
A_2 \cong 44.5 \exp[-3.712 (a/b - 1)^{0.28}] - \frac{1}{(a/b - 1)^{3/2}} \tag{5}
$$

and the effective modulus E' defined usually by

$$
E' = \begin{cases} E & \text{for plane stress} \\ E/(1 - v^2) & \text{for plane strain} \end{cases}
$$
 (6)

where E is the Young's modulus and ν the Poisson's ratio. Since plane stress prevails at a free surface, it was used $E' = E = 310$ GPa.

A representation of the displacement solution Eq. 3 is given in Fig. [2b](#page-1-0) by the dashed curves. The procedure for the determination of K_{10} may be outlined in detail for material (I). Figure 3a shows a SEM image of a Vickers indentation crack in material (I) very close to the tip. The COD were measured as a function of the distance x from the tips for several cracks. Results are plotted in Fig. 3b as the circles. The solid curve shows an average curve for the experimental data.

For an arbitrarily chosen stress intensity factor of $K = 1$ MPa_{\sqrt{m}}, the displacements were computed for any distance x by using Eqs. $3-5$. These values denoted as $2\delta_{\text{comp}}$ are taken in Fig. 4a as the abscissa. From the initially

Fig. 5 a Representation of the near-tip displacements for material (I) by a plot $\delta = f(x)$ (solid curve); dashed curve: Irwin parabola according to Eq. 7 for the same stress intensity factor value, and b results for material (II)

linear dependency between the measured and the computed displacements, the slope was determined via a least-squares fit with the fitting region $0 \le 2\delta_{\text{conn}} \le 0.025$ µm. Figure [4](#page-2-0)b shows the fitted data in more detail. The different symbols indicate different cracks. A slope of 2.33 was obtained. The dash-dotted straight lines with $\pm 15\%$ deviating slopes border the region in which 66% of the data points are located.

From the slope of 2.33 it can now simply be concluded that the related stress intensity factor in the near-tip region must be $K_{\text{I0}} = 2.33 \text{ MPa}\sqrt{\text{m}}$.

Figure 5a shows the final representation of the near-tip data of Fig. [4b](#page-2-0) with now the (linear) crack-tip distance as the abscissa. The dashed curve represents the so-called Irwin parabola, represented by Eq. [3](#page-2-0) for $A_1 = A_2 = 0$, which for $K = K_{I0}$ reads

$$
\delta = \sqrt{\frac{8}{\pi}} \frac{K_{\text{I0}}}{E} \sqrt{x} \tag{7}
$$

Application of the same evaluation procedure to the neartip displacements for material (II) result in the data of Fig. 5b providing a crack-tip toughness of $K_{10} =$ 2.0 MPa \sqrt{m} as represented by the solid curve.

Summary

Crack-tip toughness K_{10} was determined by measurement of crack opening displacement for cracks generated by

Vickers indentation tests for two $Si₃N₄$ ceramics with (Y_2O_3, MgO) and (Y_2O_3, Al_2O_3) additives.

The results were $K_{10} = 2.33 \text{ MPa} / \text{m}$ for (Y₂O₃, MgO)containing and 2.0 MPa_{\sqrt{m}} for (Y_2O_3, A_2O_3) -containing silicon nitride. Both results are in agreement with the span of literature data for other $Si₃N₄$ ceramics [1–3] which are within $1.40 \leq K_{I0} \leq 2.7$ MPa_{\sqrt{m}}.

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